

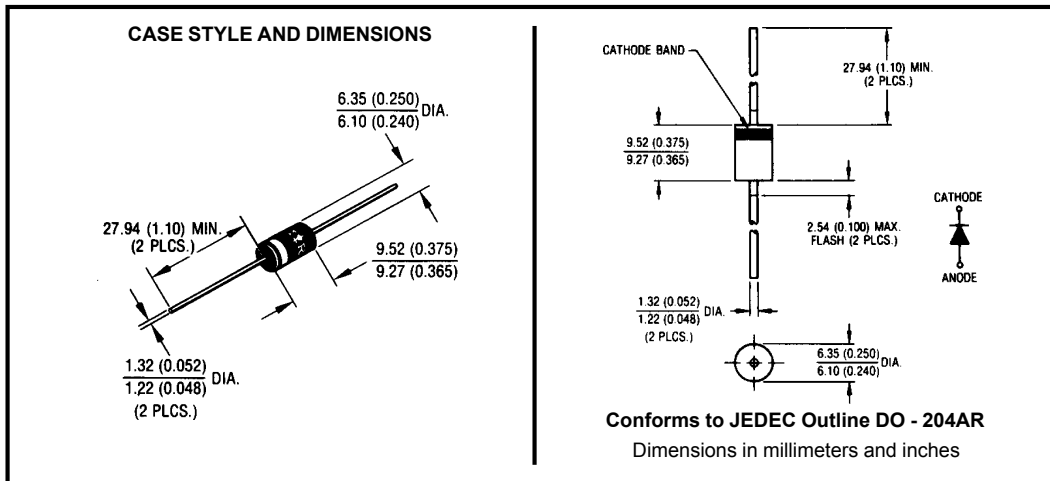
Major Ratings and Characteristics

Characteristics	80SQ...	Units
$I_{F(AV)}$ Rectangular waveform	8	A
V_{RRM} range	35 to 45	V
I_{FSM} @ $t_p = 5 \mu s$ sine	2400	A
V_F @8Apk, $T_J = 125^\circ C$	0.44	V
T_J range	-55 to 175	$^\circ C$

Description/Features

The 80SQ axial leaded Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 175° C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	80SQ035	80SQ040	80SQ045
V_R Max. DC Reverse Voltage (V)	35	40	45
V_{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

Parameters	80SQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	8	A	50% duty cycle @ $T_C = 119^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	2400	A	Following any rated load condition and with rated V_{RWM} applied
	380		
E_{AS} Non-Repetitive Avalanche Energy	10	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1.6\text{ Amps}$, $L = 7.8\text{ mH}$
I_{AR} Repetitive Avalanche Current	1.6	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	80SQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.53	V	@ 8A $T_J = 25^\circ\text{C}$
	0.60	V	@ 16A
	0.44	V	@ 8A $T_J = 125^\circ\text{C}$
	0.55	V	@ 16A
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	2	mA	$T_J = 25^\circ\text{C}$
	15	mA	$T_J = 125^\circ\text{C}$ $V_R = \text{rated } V_R$
C_T Max. Junction Capacitance	900	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	10.0	nH	Measured lead to lead 5mm from body
dv/dt Max. Voltage Rate of Change (Rated V_R)	10000	V/ μs	

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	80SQ	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 175	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 175	$^\circ\text{C}$	
R_{thJL} Max. Thermal Resistance Junction to Lead	8.0	$^\circ\text{C}/\text{W}$	DC operation * See Fig. 4 1/8 inch lead length
R_{thJA} Typical Thermal Resistance, Junction to Air		44	$^\circ\text{C}/\text{W}$
wt Approximate Weight	1.4(0.049)	g(oz.)	
Case Style	DO - 204AR	JEDEC	

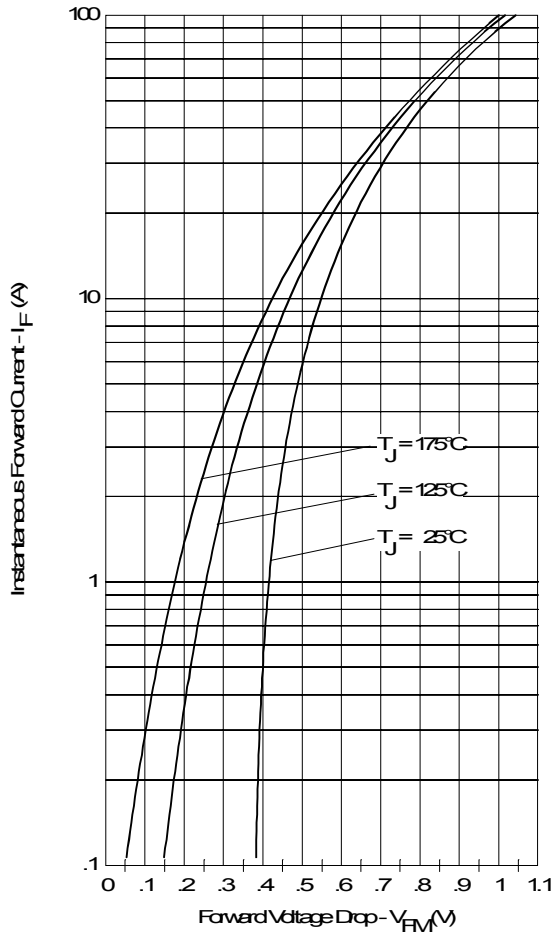


Fig. 1 - Maximum Forward Voltage Drop Characteristics

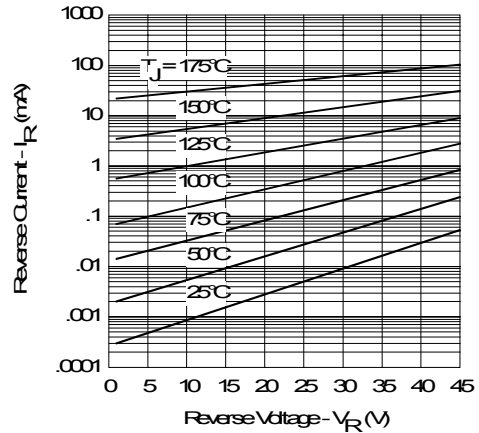


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

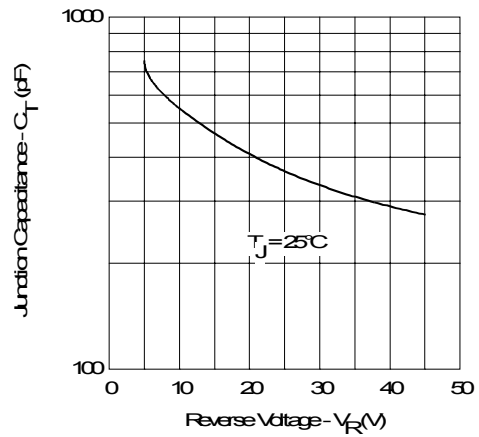


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

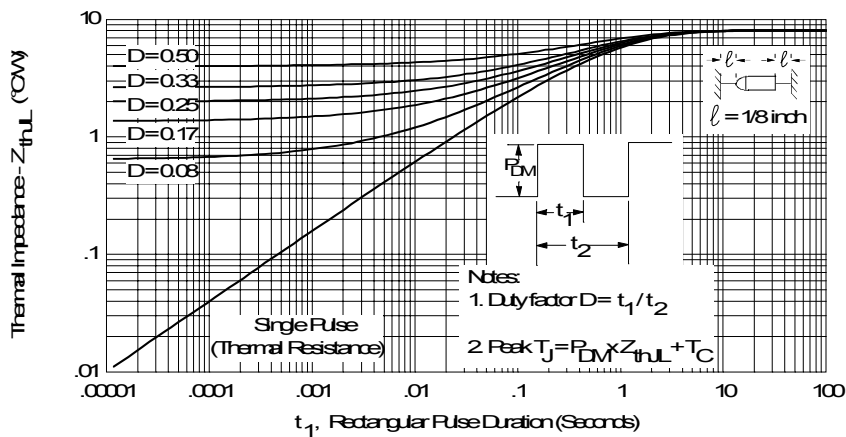


Fig. 4 - Maximum Thermal Impedance Z_{thL} Characteristics

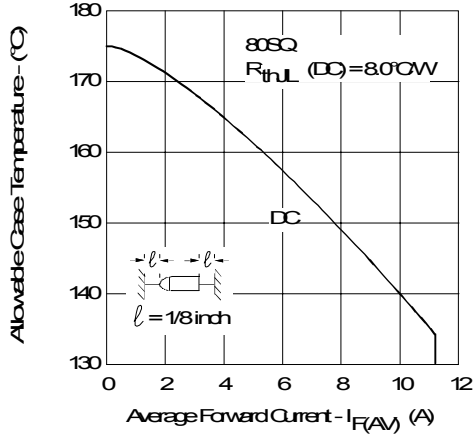


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

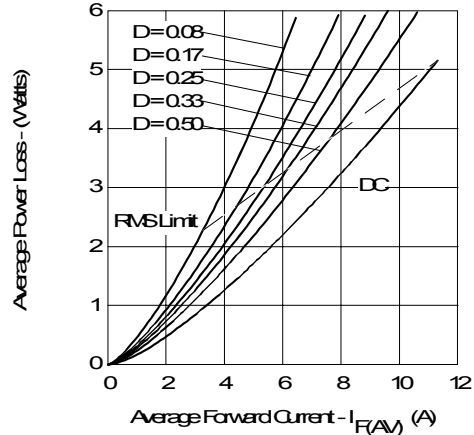


Fig. 6 - Forward Power Loss Characteristics

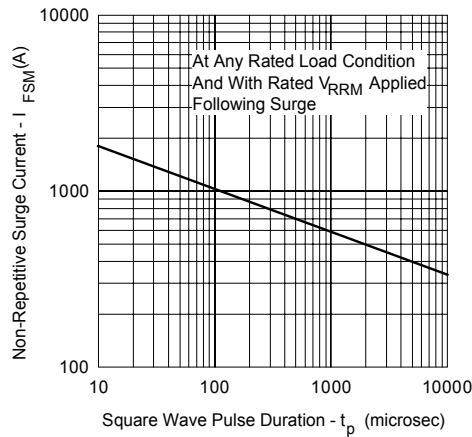


Fig. 7 - Maximum Non-Repetitive Surge Current

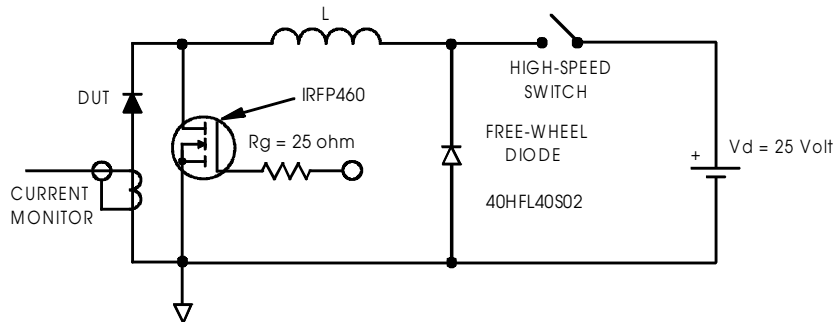
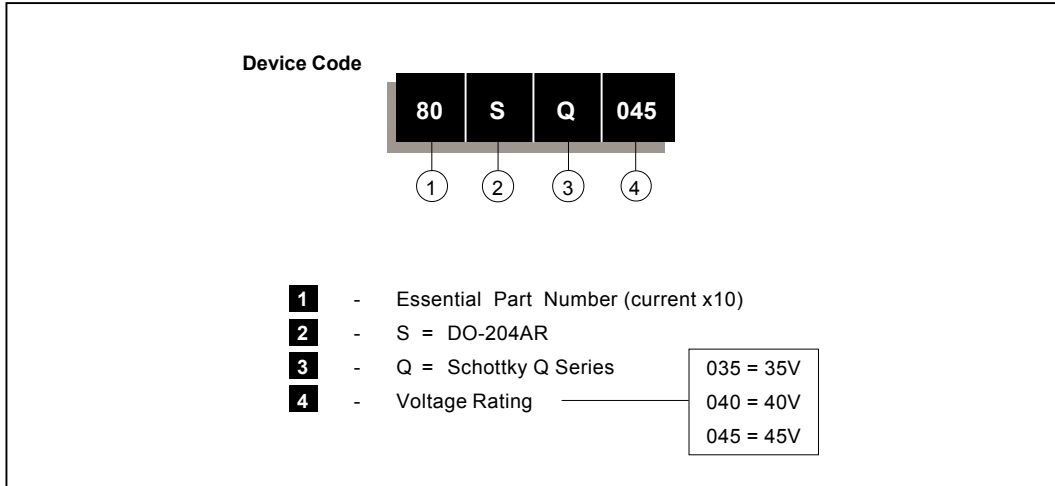


Fig. 8 - Unclamped Inductive Test Circuit

Ordering Information Table



Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.